

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912

Features

- Single power supply operation at 5.0V
- Radiation performance
 - Total dose: > 1 Mrad(Si); Dose rate = 50-300 rad(Si)/s
 - ELDRS Immune
 - SEL Immune > 100 MeV-cm²/mg
 - Neutron Displacement Damage > 10¹⁴ neutrons/cm²
- Short Circuit Tolerant
- Full military temperature range
- Designed for aerospace and high reliability space applications
- Packaging – Hermetic ceramic SOIC
 - 16-pin, .417"L x .300"W x .120"Ht
 - Weight - 0.8 grams max
- **Radiation Hardness Assurance Plan: DLA Certified to MIL-PRF-38534, Appendix G.**

General Description

The RHD5912 is a radiation hardened, single supply, quad comparator with open drain outputs in a 16-pin SOIC package. The RHD5912 design uses specific circuit topology and layout methods to mitigate total ionizing dose effects and single event latchup. These characteristics make the RHD5912 particularly suited for the harsh environment encountered in Deep Space missions. It is guaranteed operational from -55°C to +125°C. Screened in accordance with MIL-PRF-38534 Class K, the RHD5912 is ideal for demanding military and space applications.

Organization and Application

The RHD5912 quad comparator is intended for operation with dynamic signals on either or both inputs. Comparison is 'continuous', that is, the circuit functions as high gain open loop amplifiers with a digital output. For slow input signals with small input differences, the comparators can be expected to respond to small noise signals at the inputs. Although there is internal hysteresis, feedback hysteresis is the responsibility of the user to avoid 'chattering' on system noise.

The comparator will accept signals anywhere in the included power supply range. The circuit delay is specified for a half-volt single ended or differential input step of either polarity, ending in an input polarity reversal of 10mV. See Switching Diagrams.

CMOS device drive has a negative temperature coefficient and the devices are therefore inherently tolerant to momentary shorts, although on chip thermal shutdown is not provided. All inputs and outputs are diode protected.

The devices will not latch with SEU events above 100 Mev-cm²/mg. Total dose degradation is minimal to above 1 Mrad(Si). Displacement damage environments to neutron fluence equivalents in the mid 10¹⁴ neutrons per cm² range are readily tolerated. There is no sensitivity to low-dose rate (ELDRS) effects. SEU effects are application dependent.

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912

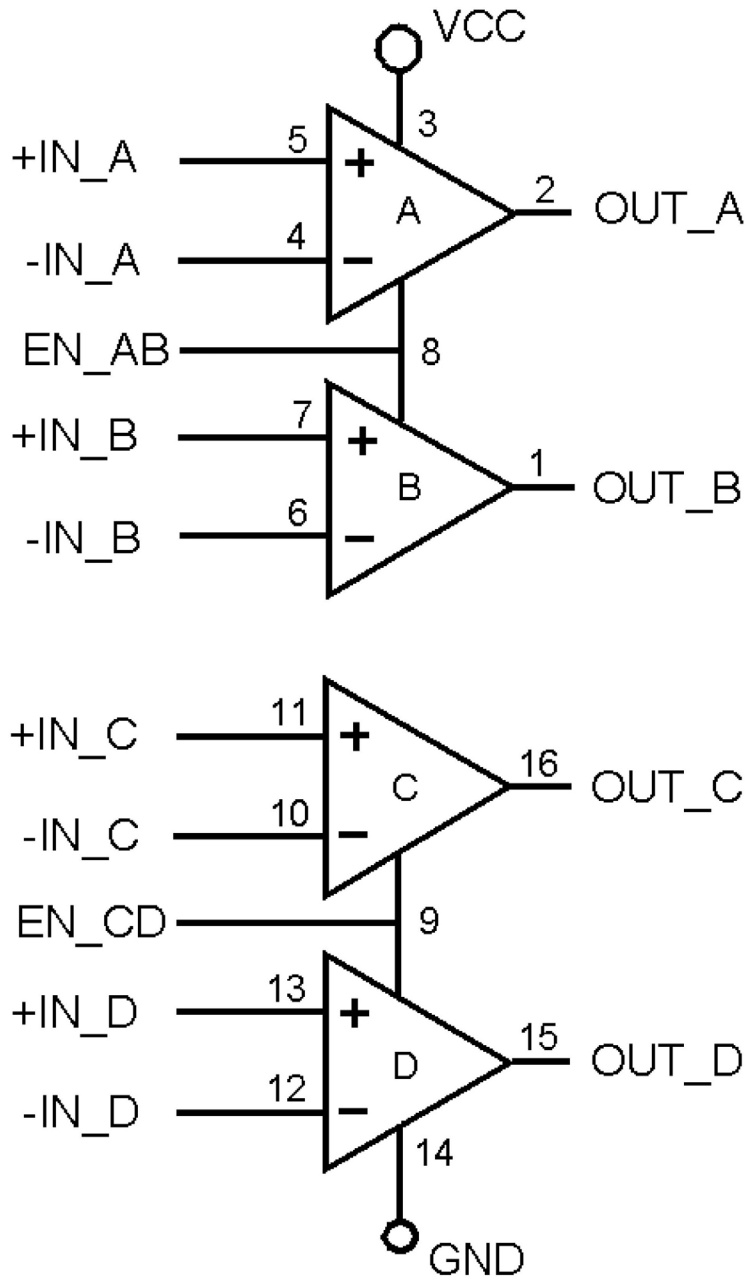
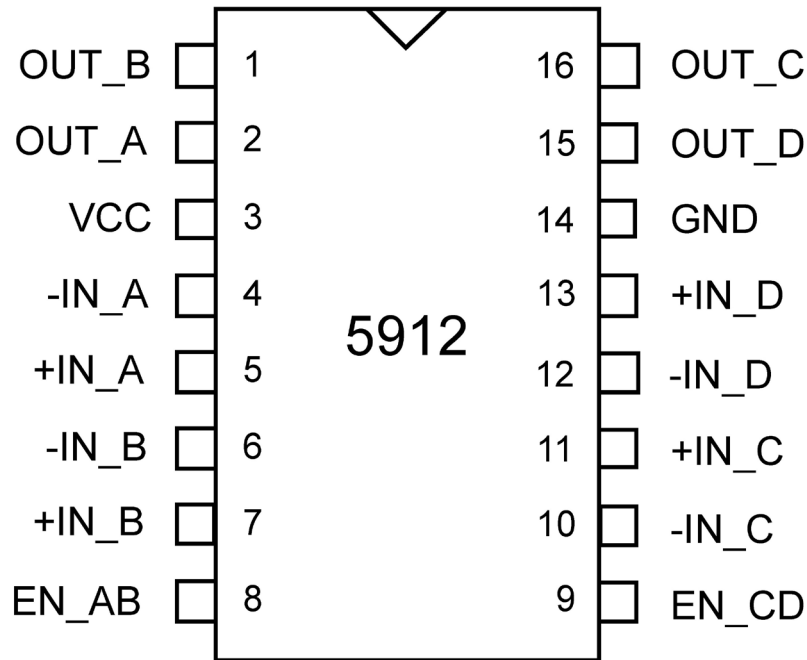


Figure 1: Block Diagram

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912



16-Pin SOIC
Figure 2: Package Pin-Out

Notes:

- 1) Package and lid are electrically isolated from signal pads.
- 2) It is recommended that the Lid be grounded to prevent any ESD or static buildup.
- 3) EN_AB enables Comparators A & B. EN_CD enables Comparators C & D.

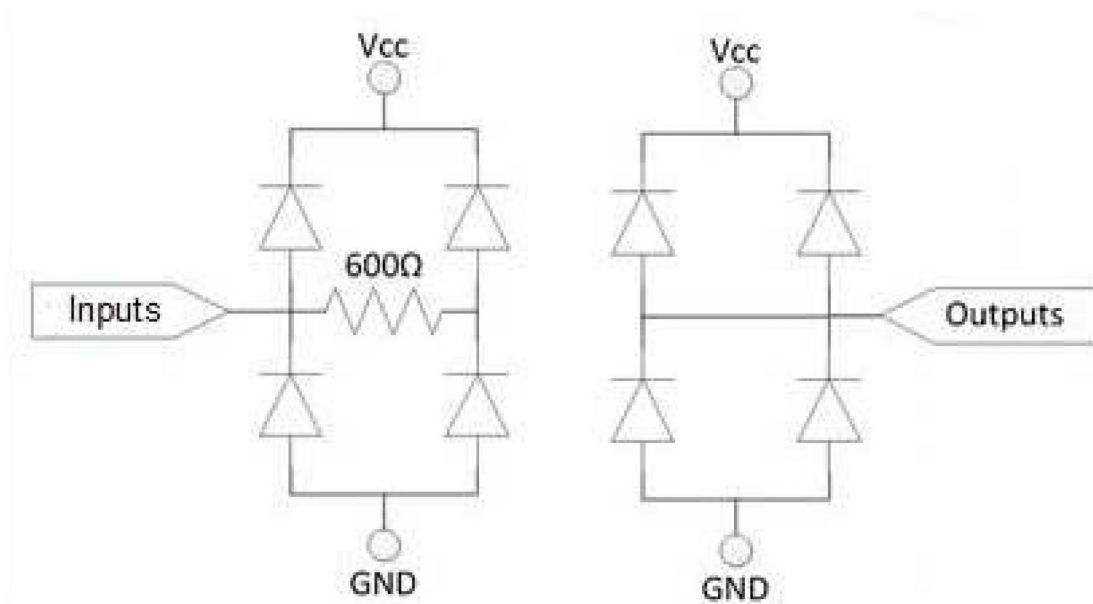


Figure 3: Diode Protection Circuits Diagram

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912

| Pin | Signal Name | Definition |
|-----|-------------|---|
| 1 | OUT_B | Output of Comparator B. |
| 2 | OUT_A | Output of Comparator A. |
| 3 | VCC | DC Supply Voltage. |
| 4 | -IN_A | Inverting input of Comparator A. |
| 5 | +IN_A | Non-Inverting input of Comparator A. |
| 6 | -IN_B | Inverting input of Comparator B. |
| 7 | +IN_B | Non-Inverting input of Comparator B. |
| 8 | EN_AB | A Logic Low will disable Comparator A & B so that the outputs are high impedance. |
| 9 | EN_CD | A Logic Low will disable Comparator C & D so that the outputs are high impedance. |
| 10 | -IN_C | Inverting input of Comparator C. |
| 11 | +IN_C | Non-Inverting input of Comparator C. |
| 12 | -IN_D | Inverting input of Comparator D. |
| 13 | +IN_D | Non-Inverting input of Comparator D. |
| 14 | GND | DC Supply Return. |
| 15 | OUT_D | Output of Comparator D. |
| 16 | OUT_C | Output of Comparator C. |

Figure 4: Pin-Out Description

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912

Absolute Maximum Ratings

| Parameter | Range | Units |
|--|----------------------------------|--------|
| Case Operating Temperature Range | -55 to +125 | °C |
| Storage Temperature Range | -65 to +150 | °C |
| Junction Temperature | +150 | °C |
| Supply Voltage (+V _{CC}) | +7.0 | V |
| Input Voltage | V _{CC} +0.4 GND -0.4 | V V |
| Input Current | ±10 | mA |
| Lead Temperature (soldering, 10 seconds) | 300 | °C |
| Thermal Resistance, Junction-to-Case θ_{JC} | 7 | °C/W |
| Power @ 25°C | 250 | mW |

Notice: Stresses listed in the "Absolute Maximum Ratings" table above may cause permanent damage to the device. These are stress rating only; functional operation beyond the "Recommended Operation Conditions" is not recommended and extended exposure beyond the "Recommended Operation Conditions" in the table below may affect device reliability.

Recommended Operating Conditions

| Symbol | Parameter | Typical | Units |
|------------------|-------------------------|--------------------------------|-------|
| +V _{CC} | Power Supply Voltage | +5.0 | V |
| V _{CM} | Input Common Mode Range | (V _{CC} - 1.5) to GND | V |

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912

Electrical Performance Characteristics(T_c = -55°C To +125°C, +V_{CC} = +5.0V -- Unless Otherwise Specified)

| Parameter | Symbol | Conditions | MIN | MAX | Units |
|---|----------------------|---|-----|------|-------|
| Quiescent Supply Current <u>1/</u> | I _{CCQ} | E _N = 1, No Load | | 3 | mA |
| | | E _N = 0 <u>2/</u> | | 300 | nA |
| Input Offset Voltage | V _{OS} | <u>4/</u> | -20 | 20 | mV |
| | | <u>1/</u> | -35 | 35 | |
| Input Offset Current <u>1/</u> , <u>3/</u> | I _{OS} | T _c = +25°C, +125°C | -10 | 10 | nA |
| Input Bias Current <u>1/</u> , <u>3/</u> | I _B | T _c = +25°C, +125°C | -10 | 10 | nA |
| Common Mode Rejection Ratio <u>1/</u> | CMRR | | 50 | | dB |
| Power Supply Rejection Ratio | PSRR | <u>4/</u> | 70 | | dB |
| | | <u>1/</u> | 60 | | |
| Output Voltage Low <u>1/</u> | V _{OL} | I _{OUT} = 5mA | | 0.25 | V |
| | | I _{OUT} = 10mA | | 0.50 | V |
| | | I _{OUT} = 20mA | | 1.00 | V |
| Gain <u>1/</u> | A | | 5 | | V/mV |
| Output Leakage Current <u>3/</u> | I _{LKOUT} | V _{OUT} = V _{CC} , T _c = +25°C, +125°C <u>4/</u> | | 100 | nA |
| | | <u>1/</u> | | 5000 | |
| Short Circuit Output Current <u>2/</u> | I _{O(SINK)} | | -35 | -60 | mA |
| Input Voltage - Enable (EN_AB, EN_CD) | V _{HI} | High (Enabled) | 3.5 | | V |
| | V _{LO} | Low (Disabled) | | 1.5 | V |
| Input Current - Enable (EN_AB, EN_CD) <u>3/</u> | I _{EN} | T _c = +25°C, +125°C | | 10 | nA |

Notes:

- 1) Specification derated to reflect Total Dose exposure to 1 Mrad(Si) @ 25°C.
- 2) Not tested. Shall be guaranteed by design, characterization or correlation to other test parameters.
- 3) Subgroup 3 for these parameters is guaranteed, but not production tested.
- 4) Specification derated to reflect Pre-irradiation to Total Dose exposure 500krad(Si) @ 25°C.

Switching Characteristics(T_c = -55°C To +125°C, +V_{CC} = +5.0V -- Unless Otherwise Specified)

| Parameter | Symbol | Conditions | MIN | MAX | Units |
|--------------------------|--------------------|------------|-----|-----|-------|
| Output Delay (Switching) | T _{OUT} | <u>1/</u> | | 300 | ns |
| Output Delay (Enabled) | t _{ONEN} | | | 500 | ns |
| Output Delay (Disabled) | t _{OFFEN} | | | 100 | ns |

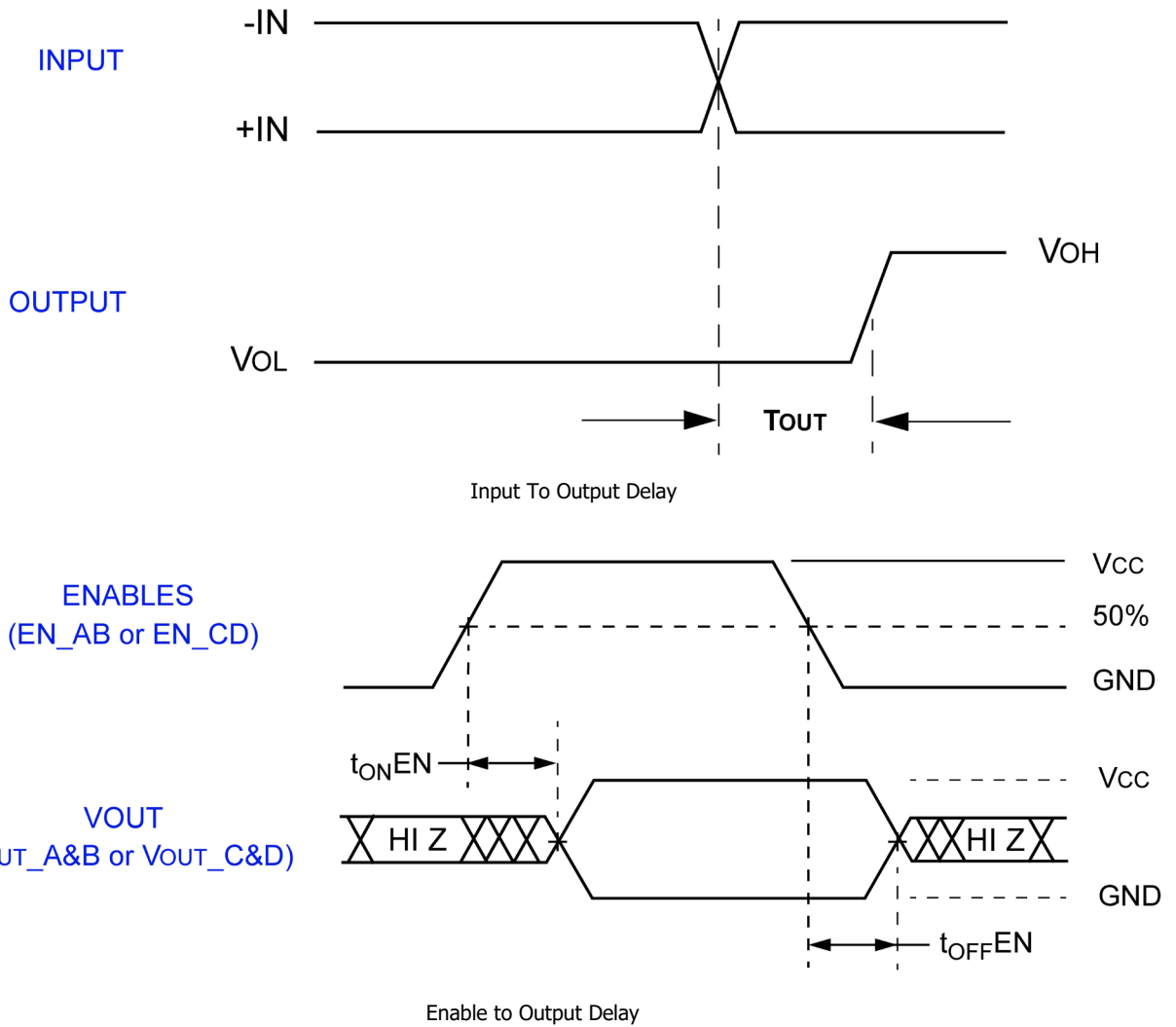
Note:

- 1) The circuit delay is specified for a half-volt single ended or differential input step, of either polarity, ending in an input polarity reversal of 10mV.

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912



Enable to Output Delay
Figure 5: RHD5912 Switching Diagrams

SCD5912

Quad Comparator, Open Drain Outputs

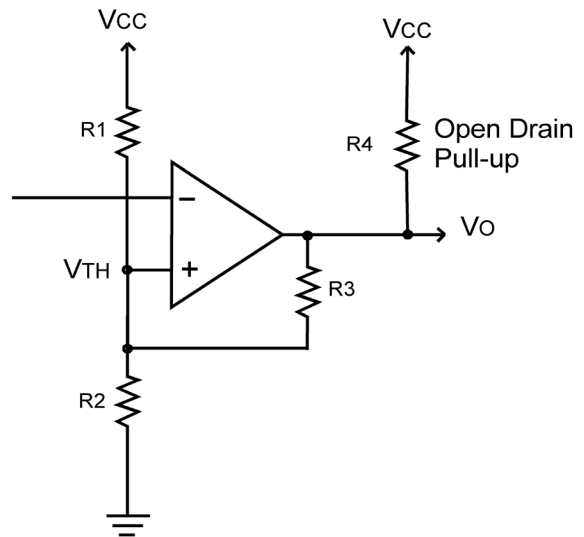
RHD5912

Threshold Voltage

$$V_{TH} = V_{CC} \frac{R2}{R1 + R2}$$

Hysteresis Calculation

$$HYS = V_O \frac{R2}{R2 + R3}$$



Application Note 1: Hysteresis

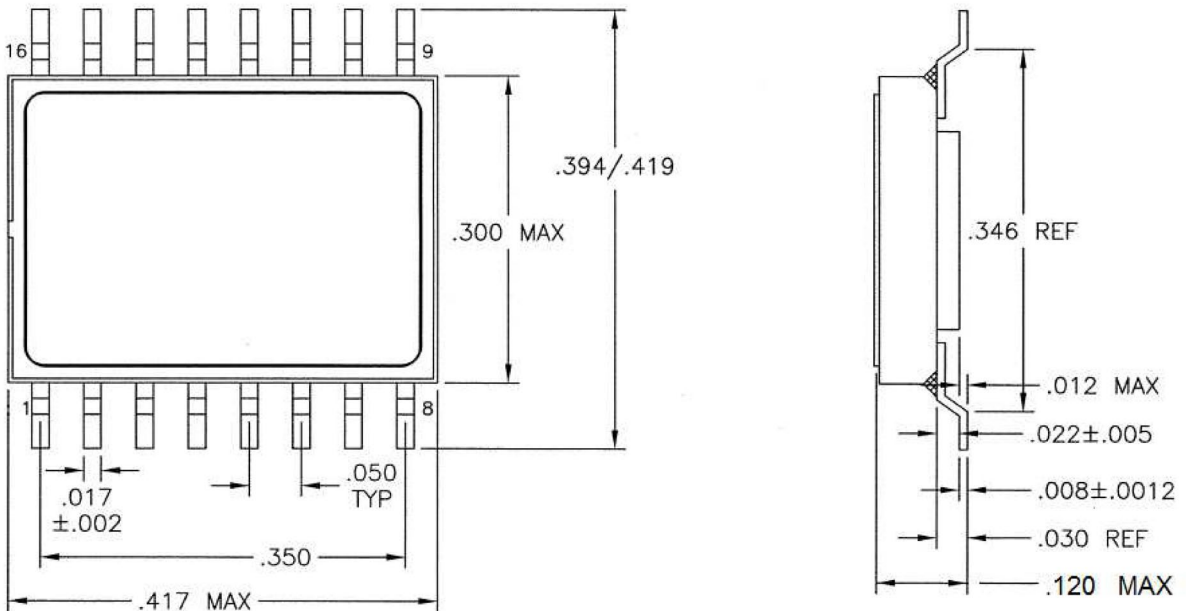


Figure 6: Package Outline

Note: Package and lid are electrically isolated from signal pads.

SCD5912

Quad Comparator, Open Drain Outputs

RHD5912

Ordering Information

| Model | DLA SMD # | Screening | Package |
|-----------------|-----------------|---|---------------------|
| RHD5912-7 | - | Commercial Flow, +25°C testing only | 16-pin SOIC Package |
| RHD5912-S | - | Military Temperature, -55°C to +125°C Screened in accordance with the individual Test Methods of MIL-STD-883 for Space Applications | |
| RHD5912- 201-1S | 5962-1024203KXC | In accordance with DLA SMD | |
| RHD5912- 201-2S | 5962-1024203KXA | | |
| RHD5912- 901-1S | 5962H1024203KXC | In accordance with DLA Certified RHA Program Plan to RHA Level "H", 1 Mrad(Si) | |
| RHD5912- 901-2S | 5962H1024203KXA | | |

Revision History

| Date | Revision | Change Description |
|------------|----------|--|
| 03/28/2016 | D | Import into CAES format |
| 06/16/2017 | E | Remove references to 3.3 volt, Add Input Current to Absolute Max table. |
| 07/20/2017 | F | Add limits for 1Mrad (Si) TID to: Input Offset Voltage, PSRR, Output Leakage Current. Change Vol (10mA) to 0.50v, add Figure 3: Diode Protection Circuit, rename Pin Out table to Figure 4, rename Switching Diagram to Figure 5, rename Package Outline to Figure 6 |



SCD5912

Quad Comparator, Open Drain Outputs

RHD5912

Revision History

| Date | Revision | Change Description |
|------------|----------|------------------------|
| 03/26/2021 | G | Revised per ECN 23566. |

Datasheet Definitions

| | DEFINITION |
|-----------------------|---|
| Advanced Datasheet | CAES reserves the right to make changes to any products and services described herein at any time without notice. The product is still in the development stage and the datasheet is subject to change . Specifications can be TBD and the part package and pinout are not final . |
| Preliminary Datasheet | CAES reserves the right to make changes to any products and services described herein at any time without notice. The product is in the characterization stage and prototypes are available. |
| Datasheet | Product is in production and any changes to the product and services described herein will follow a formal customer notification process for form, fit or function changes. |

The following United States (U.S.) Department of Commerce statement shall be applicable if these commodities, technology, or software are exported from the U.S.: These commodities, technology, or software were exported from the United States in accordance with the Export Administration Regulations. Diversion contrary to U.S. law is prohibited.

Cobham Long Island Inc. d/b/a CAES reserves the right to make changes to any products and services described herein at any time without notice. Consult an authorized sales representative to verify that the information in this data sheet is current before using this product. The company does not assume any responsibility or liability arising out of the application or use of any product or service described herein, except as expressly agreed to in writing; nor does the purchase, lease, or use of a product or service convey a license under any patent rights, copyrights, trademark rights, or any other of the intellectual rights of the company or of third parties.